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# Transition Metal Atoms Anchored on CuPS<sub>3</sub> Monolayer for Enhancing Catalytic Performance of Hydrogen Evolution Reactions

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**Abstract:** The noble metal such as Pt has been used as the catalysts for hydrogen evolution reaction (HER), but with problems such as scarcity of resources and high cost. Anchoring transition metal atoms onto the catalysts is regarded as a potential approach to solve this problem and enhance the electrocatalytic performance of HER. For this purpose, two-dimensional materials, such as CuPS<sub>3</sub> monolayer, are regarded as one of the most ideal carriers for adsorption of metal atoms. However, there is no previous study on this topic. In this paper, we systematically studied microstructures, electronic properties and electrocatalytic performance of the CuPS<sub>3</sub> monolayer anchored with transition-metal atoms (e.g., Sc, Ti, V, Cr, Mn, Fe, Co, and Ni) using a density functional theory (DFT). Results showed that all the transition metal atoms are favorably adsorbed onto the CuPS<sub>3</sub> monolayer with large binding energies at the top of the Cu atom. The pristine CuPS<sub>3</sub> monolayer has a large catalytic inertia for hydrogen evolution reactions, whereas after anchored with transition metal atoms, their catalytic performances have been significantly improved. The Gibbs free energy ( $\Delta G_H$ ) is 0.44 eV for the H atom adsorbed onto the pristine CuPS<sub>3</sub> monolayer, whereas the  $\Delta G_H$  values for

the V, Fe, and Ni atoms anchored onto the CuPS<sub>3</sub> monolayer are 0.02, 0.11, and 0.09 eV, respectively, which is close to the  $\Delta G_{\text{H}}$  of H atom adsorbed on Pt (e.g., -0.09 eV). At the same time, the influence of hydrogen coverage rate was calculated. The result shows that V adsorbed on CuPS<sub>3</sub> monolayer is catalytic active for HER for a large range of hydrogen coverage. Our results demonstrate that anchoring of V atom onto the CuPS<sub>3</sub> monolayer is a potentially superior method for making the catalyst for the HER.

**Keywords:** CuPS<sub>3</sub> monolayer; transition metal atom; hydrogen evolution reaction; density functional theory

## 1. Introduction

There are increasing concerns about the global environmental pollution, which results in a strong demand for the alternative green energy sources to replace the traditional fossil fuels [1]. As one of the promising and sustainable energy sources, hydrogen energy generated from electrocatalytic water splitting is attractive because of its simple reduction process of H<sub>2</sub>O, without much pollution generated [2]. Noble metal Pt based catalysts have shown effective stabilities for the production of H<sub>2</sub> from water through hydrogen evolution reaction (HER) [3]. However, their high cost and scarcity significantly hamper the practical applications, and thus it is critical to develop low cost and earth-abundant catalyst materials with an extraordinary electrocatalytic performance [4]. In recent years, a number of advanced non-noble catalysts for HER have been studied, such as nickel molybdenum alloys [5] dichalcogenides [6], carbides [7], nitrides [8], phosphides [9] and phosphosulfides [8].

In addition to the excellent catalytic activity, the maximum utilization of metal atoms has also been studied for HER [10-11]. Therefore, single-atom catalysts (SACs) have received extensive attention [12]. Based on references [13], individually separated atoms can improve the catalytic activity and selectivity of electrochemical reaction. However, because the high surface free energy makes these single atoms easily aggregated during the catalytic process.

Thus, single atoms should be anchored on a suitable substrate to establish a stable platform [14], which could increase atom utilization caused by the high dispersion of individual atoms [15]. As the isolated and individual metal atoms adsorbed on the substrates, the increase of catalytic active sites, the increase of unsaturated coordination number of metal atoms and the interaction between single metal atom and the substrates can lower the energy barriers of electrochemical reactions and improve the electrocatalytic activity for HER [16]. Up to now, transition-metal atoms based SACs are the hot research topic in the field of electrocatalyst for HER, such as Fe adsorbed on graphdiyne [17], Mo adsorbed on silicene [18], transition-metal atoms adsorbed on Transition Metal Dichalcogenides [19-20], and Co-Ni adsorbed on nitrogen-doped graphene [21-23].

Due to their large specific surface area and high carrier mobility, two-dimensional materials have become a good support material for SACs in recent years, such as graphene [24], silicene [25], metal sulphides[26], and metals oxides[27]. Among all two-dimensional materials, ternary metal thiophosphates as the supports for the SACs was rarely studied. Recently, Xiao et al prepared Ni atom anchored onto FePS<sub>3</sub> nanosheets which enhanced water adsorption and dissociation process, thus accelerating the HER [28]. Strong interactions between Ni atom and FePS<sub>3</sub> nanosheets can tune the electronic structures of FePS<sub>3</sub> nanosheets. Hence, the catalytic activity of HER for FePS<sub>3</sub> was improved [28]. Until now, the CuPS<sub>3</sub> monolayer as the support for the adsorption of transition-metal atoms has not been reported. As a member of the family of ternary metal thiophosphates, CuPS<sub>3</sub> has similar electrochemical properties compared to those of FePS<sub>3</sub> and can be considered as a support material for transition-metal atoms. CuPS<sub>3</sub> monolayer is composed of Cu and P atoms in an octagonal structure of S atoms, and have Cu and P atoms between two sheets of S atoms [29]. This structure provides a large specific surface area and many adsorption sites for transition-metal atoms to be anchored and thus achieves a good thermodynamic stability [30]. CuPS<sub>3</sub> monolayer can be easily obtained by exfoliating their bulk counterpart into a layered structure due to the van der Waals (vdW) interactions between each layers, which opens up the possibility of mass productions [31]. Inspired by the above, it is critical to adjust the surface catalytic site and electronic structure of CuPS<sub>3</sub>

monolayer to enhance its catalytic activity for HER.

Herein, the structures, electronic properties and electrocatalytic performance of a CuPS<sub>3</sub> monolayer anchored with transition-metal atoms (e.g., Sc, Ti, V, Cr, Mn, Fe, Co, and Ni) were investigated using a density functional theory (DFT). Results showed that all the transition metal atoms are favorably adsorbed onto the CuPS<sub>3</sub> monolayer with large binding energies. The pristine CuPS<sub>3</sub> monolayer has a large catalytic inertia for HER, whereas their catalytic performance has been significantly improved after anchored with transition metal atoms. Among them, the adsorption Gibbs free energies ( $\Delta G_H$ ) for the V, Fe, and Ni atoms anchored onto the CuPS<sub>3</sub> monolayer are 0.02, 0.11, and 0.09 eV, respectively. The values of the  $\Delta G_H$  are comparable to precious metal catalyst [32]. At the same time, the influence of hydrogen coverage rate was calculated. The result shows that V adsorbed on CuPS<sub>3</sub> monolayer is catalytic active for HER for a large range of hydrogen coverage. Our results suggest that anchoring of V atom on CuPS<sub>3</sub> monolayer represents a new generation of catalyst for hydrogen evolution reaction.

## 2. Computational Details

All the DFT calculations were performed with the SIESTA code [33], using the generalized gradient approximation with the scheme of Perdew-Burke-Ernzerhof (GGA-PBE) functional [34]. Norm-conserving pseudopotentials were used to describe the electron-ion interactions, and double- $\zeta$  basis sets with the polarization function (DZP) were used to describe the valence electron wave functions [33]. The conjugate gradient (CG) method was used for the structural optimizations, and the Brillouin zone was sampled by  $15 \times 15 \times 1$  k-point mesh within the Monkhorst-Pack(MP) scheme [35]. The atomic positions and lattice parameters were fully relaxed until the force on each atom was less than 0.01 eV/Å. A vacuum of thickness 30 Å was added perpendicular to the surface of monolayer to avoid any spurious periodic interactions.

Under the standard conditions, the HER involves two elementary reaction steps. The first step is the Volmer step in which intermediate hydrogen adsorption ( $H^+ + e^- + * = H^*$ ) occurs, and the second step is that molecular hydrogen is generated and leaves the catalyst site through

Heyrovsky step ( $H^*+H^++e^-=H_2+*$ ) [36] or Tafel step ( $2H^*=H_2+2*$ ). Thus, the overall HER can be described using the following equation under standard conditions:



In this equation, an initial state  $H^+(aq) + e^-$ , an intermediate adsorbed  $H^*$ , and the final product  $1/2H_2(g)$  are involved in the HER. The basic notion is that  $\Delta G_H = 0$  is a necessary condition (but not sufficient) for a good catalyst [37-38]. The HER performance for the transition metal atoms decorated on the  $CuPS_3$  monolayer can be evaluated by computing the adsorption Gibbs free energy ( $\Delta G_H$ )[39]. The value of  $\Delta G_H$  for an ideal catalyst for HER should be close to zero [40] for the formation of intermediate state  $H^*$  and the easy release of  $H_2$ .  $\Delta G_H$  can be calculated using the following equation:

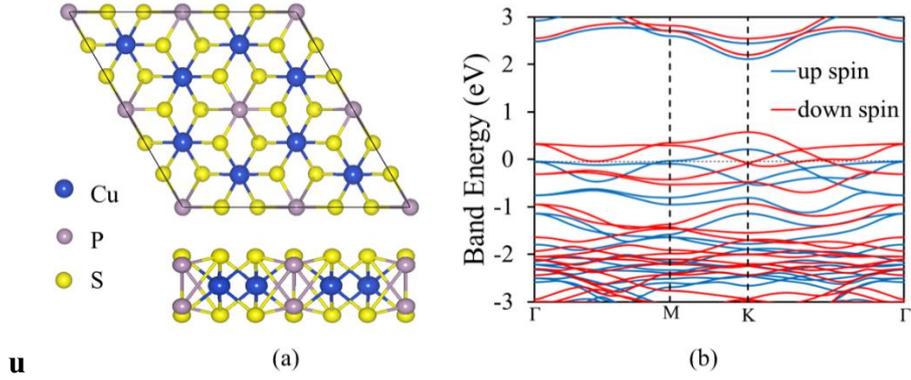
$$\Delta G_H = \Delta E_H + \Delta E_{ZPE} - T\Delta S_H \quad (2)$$

where  $\Delta E_{ZPE}$  is the difference of zero-point energies between the adsorption state and the gas phase of  $H_2$ , and  $\Delta S_H$  is the difference of entropy values between the adsorption state and the gas phase of  $H_2$ . At a temperature of 300 K and an atmospheric pressure of 1 bar, the value of  $-T\Delta S_H$  of  $H_2$  is calculated to be 0.20 eV [41].  $\Delta E_H$  can be calculated by the equation (3)

$$\Delta E_H = E_{*H} - E_* - \frac{1}{2}E_{H_2} - E_{BSSE} \quad (3)$$

where  $E_{*H}$  and  $E_*$  are the total energies of  $CuPS_3$  monolayer with and without hydrogen adsorption, respectively.  $E_{H_2}$  is the total energy of hydrogen molecule in the gas phase [40].  $E_{BSSE}$  is the basis set superposition error (BSSE) caused by the artificial shortening of distances and enhanced interactions, which can be corrected by applying the counterpoise corrections using 'ghost' atoms [42-43].

### 3. Results and discussion



**Figure 1.** (a) Top and side views of pristine CuPS<sub>3</sub> monolayer. (b) The calculated band structure of pristine CuPS<sub>3</sub> monolayer.

Figure 1(a) shows the top view and side view of the pristine CuPS<sub>3</sub> monolayer. The Cu atoms are located in the middle of the monolayer and arrange in a hexagonal lattice. The P<sub>2</sub> dimers are located at the hexagonal center of Cu honeycomb lattice and are above and below the Cu plane. The Cu atoms and P<sub>2</sub> dimers are surrounded by six S atoms forming an octahedral complex. After the structural optimization using the DFT calculations, the lattice parameter of CuPS<sub>3</sub> monolayer is found to be  $a=b=5.90$  Å, and the (P-P) distance between the phosphorous atoms is 2.22 Å. The (Cu-Cu) distance between copper atoms is 3.39 Å, and the (P-S) distance between a phosphorous atom and a sulfur atom is 2.07 Å. All these results are consistent with those reported in Ref. [29].

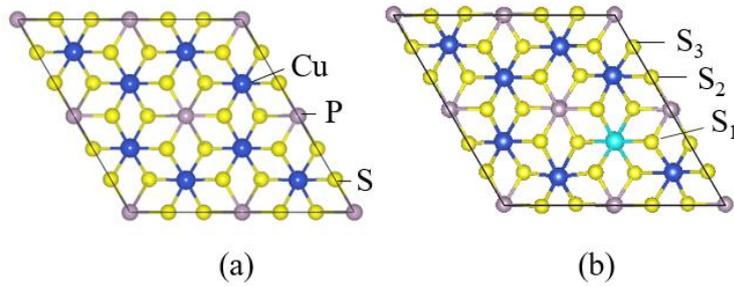
For monolayers of different ternary metal phosphosulfide compounds, the S<sup>2-</sup> ions of the plane structure remain the constant, but the P-P distances are elongated in order to accommodate the metal atoms. The P-P distance in the CuPS<sub>3</sub> monolayer is slightly larger than that in NiPS<sub>3</sub> (2.15 Å) and equal to that in CdPS<sub>3</sub> (2.22 Å) [44]. Figure 1(b) shows the band structure of the optimized CuPS<sub>3</sub> monolayer, indicating that the CuPS<sub>3</sub> monolayer is a semiconductor material. The direct bandgap of CuPS<sub>3</sub> monolayer is 1.63 eV, and the conduction band minimum (CBM) and the valence band maximum (VBM) are located at the K point, which is in agreement with the previously reported theoretical calculated value of 1.76 eV [29]. Meanwhile, the plot of its projected density of states (PDOS) reveals its conductor

characteristics. The PDOS results show that the energy splitting between the spin-up and spin-down occurs near the Fermi energy level, which is about 0.12 eV. The orbital of S 3p contributes most of the total density of states in the Fermi energy level. The metallic characteristic of CuPS<sub>3</sub> monolayer facilitates the transportation of electrons, which is beneficial for HER process [6].

Figure 2(a) shows possible positions for the adsorption of transition metal atoms on CuPS<sub>3</sub> monolayer, including the top of the copper atom (Cu), the top of the phosphorous atom (P), and the top of the S atom (S). The other possible sites were also tested, but they were all relaxed to one of the above three sites. The binding energy was calculated using the equation (5) to evaluate the stability of transition metal atoms adsorbed on the CuPS<sub>3</sub> monolayer,

$$E_{ads} = E_{adatom} + E_{CuPS_3} - E_{adatom@CuPS_3} \quad (5)$$

where  $E_{adatom}$  is the energy of a transition metal atom,  $E_{CuPS_3}$  is the total energy of pristine CuPS<sub>3</sub> monolayer after optimization, and  $E_{adatom@CuPS_3}$  is the total energy of the transition metal atom adsorption system. According to Equation (5), the more positive the binding energy is, the better the adsorption of transition metal atoms on the CuPS<sub>3</sub> monolayer will be. The larger the binding energy is, the more stable the transition metal atom adsorption system, which was also reported in Ref. [45]. The calculated binding energies of the transition metal atom adsorption systems after their full optimizations are listed in Table 1. The calculated results showed that the Cu site is the optimum energy adsorption site for all the studied transition metal atoms. The binding energies are 8.98, 10.34, 11.32, 12.50, 13.20, 11.39, 10.89, and 8.71 eV for the systems based on Sc, Ti, V, Cr, Mn, Fe, Co, and Ni atoms, respectively. The strong binding of transition metal atoms and the 2D layer is beneficial for various physical and chemical applications.



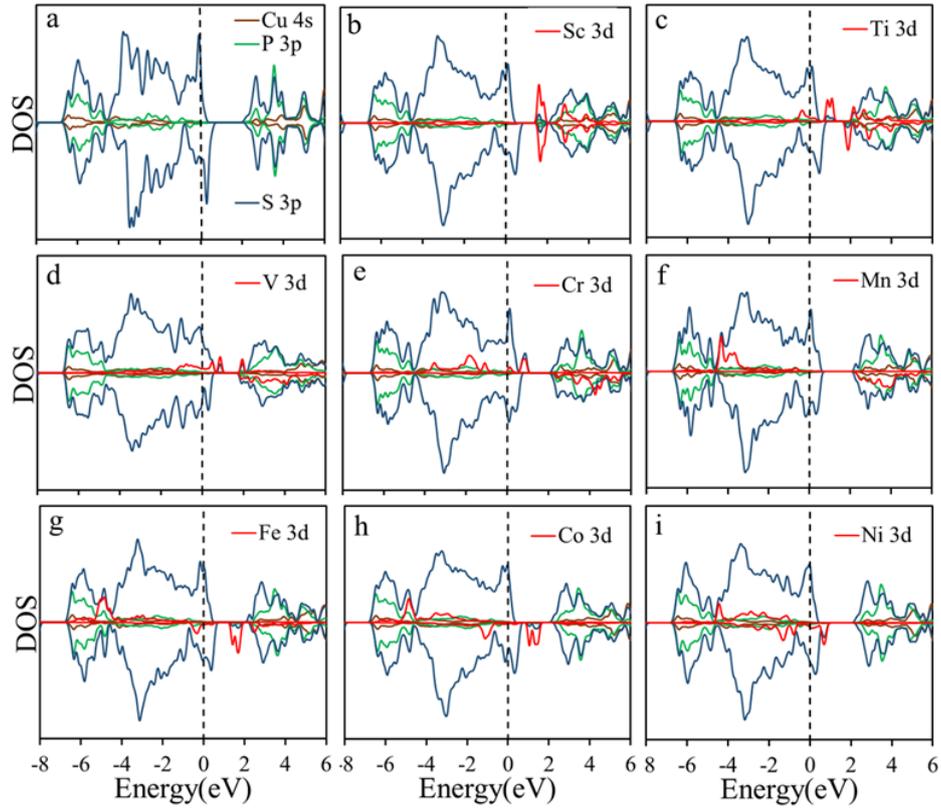
**Figure 2.** (a) The possible adsorption sites of transition metal atoms in the CuPS<sub>3</sub> monolayer. (b) The possible adsorption positions of H atom on the transition metal atoms adsorption system.

The PDOS results of pristine and transition metal atoms decorated CuPS<sub>3</sub> monolayer are shown in Figure 3. The electronic structure of the CuPS<sub>3</sub> monolayer near the Fermi level has apparently been changed by the adsorbed transition metal atoms.

For the Sc atoms adsorbed on the CuPS<sub>3</sub> monolayer (figure 3(b)), the peak of spin-up and spin-down Sc 3d states appears at about 1.49 eV, which is higher than the Fermi energy level. Meanwhile, the electronic states of P 3p and Cu 4s remain similar values compared with that of the pristine CuPS<sub>3</sub> except the monolayer's Fermi energy level is shifted up about 0.32 eV, which is due to the charge transfer from Sc to S atoms in the CuPS<sub>3</sub> monolayer.

**Table 1** Calculated binding energies (eV) for transition metal atoms adsorption system, and the catalytic active sites for HER with the Gibbs free energies for hydrogen adsorption.

	Binding energies (eV)			Optimum site	Adsorption site	HER			
	Cu	P	S			$\Delta G_H$ (eV)	$\Delta G_{2H}$ (eV)	$\Delta G_{4H}$ (eV)	$\Delta G_{6H}$ (eV)
Sc	8.98	5.73	8.97	Cu	S <sub>3</sub>	0.21	-	-	-
Ti	10.34	7.11	10.34	Cu	S <sub>1</sub>	0.28	-	-	-
V	11.32	8.89	9.88	Cu	S <sub>3</sub>	0.02	0.03	0.05	-0.10
Cr	12.50	10.35	10.35	Cu	S <sub>3</sub>	0.18	-	-	-
Mn	13.20	10.78	12.01	Cu	S <sub>3</sub>	0.35	-	-	-
Fe	11.39	9.11	10.29	Cu	S <sub>3</sub>	0.11	0.47	1.23	1.53
Co	10.89	7.96	9.41	Cu	S <sub>3</sub>	0.18	-	-	-
Ni	8.71	6.42	7.61	Cu	S <sub>3</sub>	0.09	1.60	1.18	1.25
pristine	-	-	-	-	-	0.44	-	-	-



**Figure 3.** Projected density of states (PDOS) plots for pristine CuPS3 (a), Sc (b), Ti (c), V (d), Cr (e), Mn (f), Fe (g), Co (h), and Ni (i) on CuPS3 monolayer at Cu site. The up and down plots present the spin-up and spin-down states, respectively.

For the Ti atom adsorbed on the Cu site of the CuPS<sub>3</sub> monolayer (figure 3(c)), the Fermi energy level is also shifted up by about 0.32 eV compared with that of the pristine CuPS<sub>3</sub> monolayer. There are two peaks of the spin-up and spin-down total states, contributed by the Ti 3d states, and they are located at 1.85 eV and 1.99 eV above Fermi energy  $E_F$ , respectively.

For the V atom adsorbed at the Cu site of the CuPS<sub>3</sub> monolayer (figure 3(d)), the hybridization between the spin-up V 3d states and the S 3p states occurs near and below  $E_F$ . There exist two strong interactions between the spin-up V 3d states and the S 3p states, which occur at 0.78 eV and 1.86 eV, respectively. There are also three spin-down DOS peaks due to the hybridization between the V 3d states and the S 3p states, all above  $E_F$ . The electron states of V atom 3d orbital near  $E_F$  can effectively improve the electron domination and optimize the HER catalytic activity.

For the Cr atoms adsorbed on the CuPS<sub>3</sub> monolayer, they are strongly bound within the plane of this monolayer. Four main DOS peaks due to the hybridization of Cr 3d states and S 3p states are located below and around  $E_F$  for the spin-up state, as shown in figure 3(e). Two main spin-up Cr 3d peaks are located above  $E_F$ . At the same time, the Fermi energy level is shifted up by 0.25 eV.

For the Mn atom adsorbed on the CuPS<sub>3</sub> monolayer, there is a strong hybridization of spin-up Mn 3d states and S 3p states, which is located at 4.54 eV below the Fermi energy level as shown in figure 3(f). The spin-down Mn 3d peak appears above  $E_F$  in the range of 2.20 eV to 3.98 eV. The interaction is much weaker for the spin-down state than that for the spin-up state.

As shown in figures 3(g) and 3(h), there are two spin-up and spin-down DOS peaks for the Fe and Co atoms on the CuPS<sub>3</sub> monolayer. Among them, the spin-up peaks are contributed by the strong hybridization between the transition metal atom 3d states and S 3p states. The peak of Fe 3d orbital near  $E_F$  accelerates electron transfer during the catalytic process, which is beneficial to HER catalysis.

For the Ni atoms adsorbed on the CuPS<sub>3</sub> monolayer, there is an energy range from -4.81 eV to 0.98 eV for the hybridization of the Ni 3d states and S 3p states in Figure 3(i). The 3d orbital of Ni atom is hybridized with the 3p orbital of P atom, and thus the Ni atoms are effectively adsorbed on the surface of CuPS<sub>3</sub> monolayer. In addition, Ni 3d orbit has a large peak near the Fermi energy level, which is beneficial for the electron transport in the catalytic process and thus the HER catalytic performance.

The catalytic performances of CuPS<sub>3</sub> monolayer decorated with the transition metal atom as the catalysts for HER were further evaluated by comparing their Gibbs adsorption free energies. In this study, a 2×2 supercell of pristine CuPS<sub>3</sub> was employed to model the basal plane. The calculation results show that the top of the S atom is more energetically favorable for the H adsorption. The  $\Delta G_H$  is 0.44 eV for the H atom adsorbed onto the pristine CuPS<sub>3</sub> monolayer. Therefore, the H atom is difficult to be bound to the CuPS<sub>3</sub> monolayer because of its higher Gibbs free energy, which indicates that the pristine CuPS<sub>3</sub> monolayer has a poor catalytic

performance for HER. For the transition metal atoms adsorbed onto the CuPS<sub>3</sub> monolayer system, there are three possible adsorption sites for H atoms, i.e. on the top of the S atom (S<sub>1</sub>, S<sub>2</sub> and S<sub>3</sub>) with different distances to the transition metal atom as shown in figure 2(b).

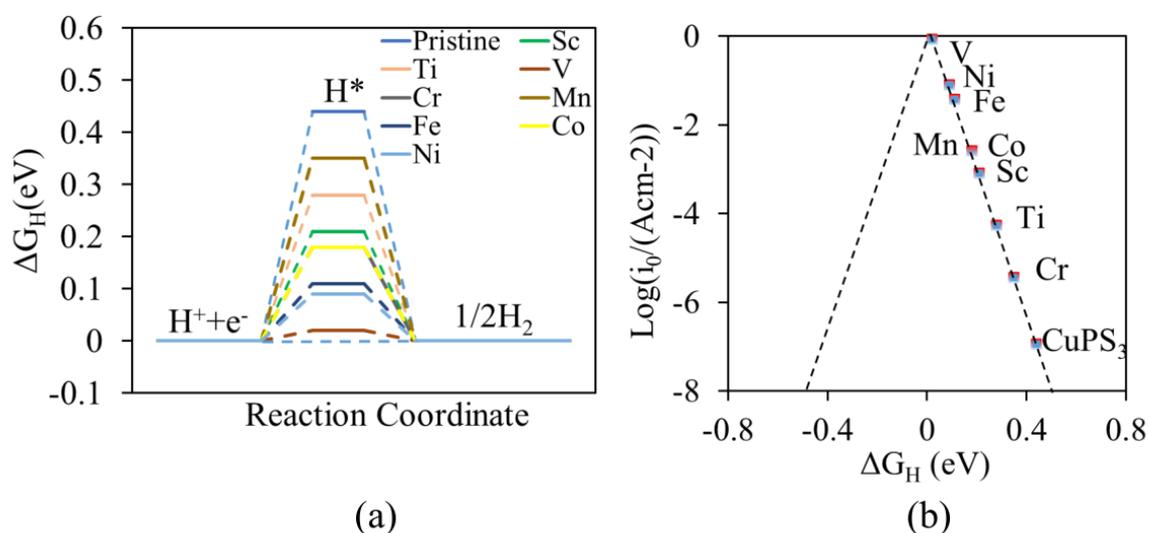
The Gibbs free energy values calculated by the density functional theory and the optimal adsorption sites of H atom on the transition metal atom system are listed in Table 1. The adsorption Gibbs free energy diagrams of HER on the pristine CuPS<sub>3</sub> pristine monolayer and transition metal decorated ones are shown in figure 4(a). The obtained values of  $\Delta G_H$  for Sc, Ti, V, Cr, Mn, Fe, Co, and Ni adsorbed on the CuPS<sub>3</sub> monolayer are 0.21, 0.28, 0.02, 0.18, 0.35, 0.11, 0.18, and 0.09 eV, respectively. Among all the transition metal atoms, the  $\Delta G_H$  values of V, Fe, and Ni atoms decorated CuPS<sub>3</sub> monolayer on the active site of S<sub>3</sub> are close to zero, indicating that the V, Fe, and Ni decorated CuPS<sub>3</sub> monolayers show good catalytic activities for the HER. Compared with the above results, the active site of the previously reported Ni adsorbed on FePS<sub>3</sub> monolayer at S<sub>1</sub> site is different with the Ni adsorbed on CuPS<sub>3</sub> monolayer, and the Gibbs free energy is 0.20 eV [28]. Theoretically Ni adsorbed on CuPS<sub>3</sub> monolayer has potentially higher HER catalytic activity than on FePS<sub>3</sub> monolayer. It was reported that the states around Fermi energy level is conducive to the adsorption of H, which will increase the catalytic activity of the material [46]. From the above results, the 3d states peaks of V and Ni atoms are closer to the Fermi energy level than those of the other atoms, therefore, the V, Fe, and Ni decorated systems have potentially better catalytic performance than the other transition metal atoms for HER.

Based on Norskov's hypothesis [47], the catalytic performance of a catalyst for HER can be analyzed. The theoretical exchange current  $i_0$  was calculated using the average Gibbs free energy of hydrogen adsorption on the catalyst [42]. The value of  $i_0$  can be calculated using equations (6) and (7) for  $\Delta G_H > 0$  and  $\Delta G_H < 0$ , respectively, at pH = 0,

$$i_0 = -ek_0 \frac{1}{1 + \exp(\Delta G_H/k_bT)} \quad (6)$$

$$i_0 = -ek_0 \frac{1}{1 + \exp(-\Delta G_H/k_bT)} \quad (7)$$

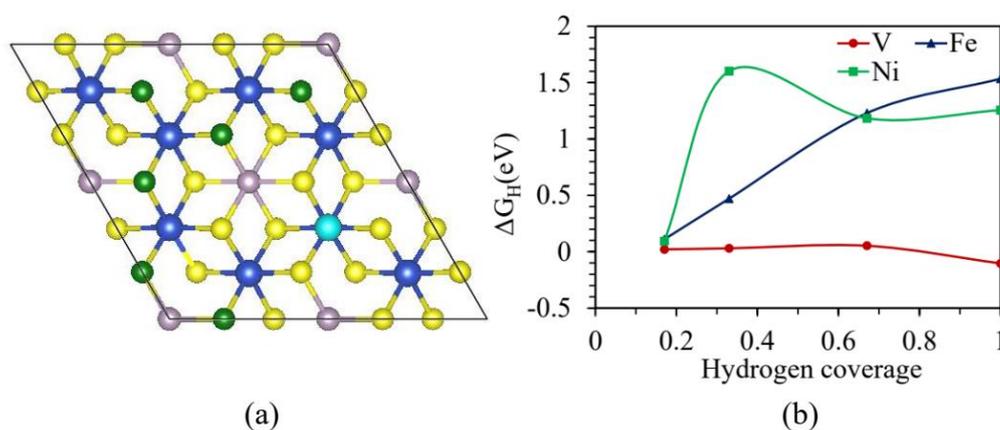
where  $k_0$  is the reaction rate constant at zero overpotential,  $k_b$  is the Boltzmann constant, and  $T$  is the temperature. The obtained diagrams are plotted in figure 4(b). In this figure, the positions of  $i_0$  and the values of  $\Delta G_H$  for the catalysts reveal their catalytic performance for HER. The left side of the volcano curve shows the negative values of  $\Delta G_H$  and the right side is corresponding to positive values of  $\Delta G_H$ . The value of  $\Delta G_H$  is zero at the top of the peak, which means that the closer to the top of the peak position, the better the HER performance of the catalyst [48]. As shown in figure 4(b), the  $\Delta G_H$  values for the V, Fe, and Ni atom decorated CuPS<sub>3</sub> monolayer are located very close to the position of the volcano peak, indicating that these atoms anchored CuPS<sub>3</sub> monolayers are potentially good catalysts for HER. The rest of transition metal atoms adsorption system are located on the right of the curve as shown in figure 4(b), which are all far away from the position of the peak, indicating that the hydrogen atoms are difficult to be adsorbed onto the catalysts and they have weak catalytic effects on HER.



**Figure 4.** (a) The adsorption Gibbs free energy diagram of HER at the equilibrium potential transition-metal atoms anchored on the CuPS<sub>3</sub> monolayer. (b) The volcano curve of exchange current as a function of the adsorption Gibbs free energy.

The effect the adsorption free energy of hydrogen coverage of H atom adsorption on electrocatalyst were further investigated. The hydrogen coverage ratio ( $\theta_H$ ) is defined as the

ratio between the number of adsorbed H atoms ( $n$ ) and the number of catalytic active sites ( $m$ ),  $\theta_H = n/m$ . The catalytic active sites of H atom on the catalyst surface are shown in Figure 5(a), and the Gibbs free energies for different hydrogen coverage ratio are shown in Figure 5(b). The Gibbs free energies of hydrogen coverage for V, Fe and Ni are listed in Table 1. For Fe and Ni adsorbed on CuPS<sub>3</sub> monolayer, the Gibbs free energy increases with the increase of hydrogen atomic coverage, indicating that Fe and Ni adsorbed on CuPS<sub>3</sub> monolayer are inert for HER for a large range of hydrogen coverage. However, for the V adsorbed on CuPS<sub>3</sub> monolayer, the Gibbs free energies for H atom adsorption are in the range from -0.10 to 0.02 eV for different hydrogen coverage ratios. The results prove that V adsorbed on CuPS<sub>3</sub> monolayer is catalytic active for HER for a large range of hydrogen coverage.



**Figure 5.** (a) The catalytic active sites of H atom on the Fe Ni and V adsorbed on CuPS<sub>3</sub> monolayer. The green atom is H atom. (b) The Gibbs free energy of H atom adsorption on the Fe Ni and V adsorbed on CuPS<sub>3</sub> monolayer as function of hydrogen coverage.

#### 4. Conclusion

In brief, in this paper, electronic properties and the catalytic performance of HER for the CuPS<sub>3</sub> monolayer decorated by transition metal atoms were studied using the DFT calculation. Results show that all the transition metal atoms are closely bound to the Cu sites with a high binding energy. The pristine CuPS<sub>3</sub> monolayer has a poor catalytic performance for HER, and anchoring of transition metal atoms onto it can improve the catalytic performance of CuPS<sub>3</sub> monolayer. Among all these transition metal atoms, the values of  $\Delta G_H$  for the systems of V, Fe and Ni atoms are 0.02, 0.11 and 0.09 eV, respectively, which indicate the significantly improved

catalytic performance of HER of CuPS<sub>3</sub> monolayer. At the same time, the influence of hydrogen coverage rate was calculated. The result shows that V adsorbed on CuPS<sub>3</sub> monolayer is catalytic active for HER for a large range of hydrogen coverage. This work provides a fundamental design methodology on how to improve the catalytic activity of catalysts based on monolayers of ternary metal phosphorus sulfide compounds.

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**Conflict of Interest:** The authors declare that they have no conflicts of interest.

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